

Continental Device India Limited

An ISO/TS16949 and ISO 9001 Certified Company



NPN SILICON PLANAR SWITCHING TRANSISTORS

2N2221 2N2222

TO-18 Metal Can Package

General Purpose Transistor

ABSOLUTE MAXIMUM RATINGS

| DESCRIPTION | SYMBOL | VALUE | UNIT |
|--|-----------------|--------------|--------|
| Collector Emitter Voltage | V_{CEO} | 30 | V |
| Collector Base Voltage | V_{CBO} | 60 | V |
| Emitter Base Voltage | V_{EBO} | 5 | V |
| Collector Current Continuous | I _C | 800 | mA |
| Power Dissipation @ T _a =25°C | P_{D} | 500 | mW |
| Derate Above 25°C | | 2.85 | mW/ °C |
| Power Dissipation @ T _c =25°C | P_{D} | 1.2 | W |
| Derate Above 25°C | | 6.85 | mW/ °C |
| Operating And Storage Junction Temperature Range | T_{j},T_{stg} | - 65 to +200 | °C |

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

| , | • | , , , , , , , , , , , , , , , , , , , | | | | |
|---------------------------|-------------------|---|-----|-----|-----|------|
| DESCRIPTION | SYMBOL | TEST CONDITION | MIN | TYP | MAX | UNIT |
| Collector Emitter Voltage | *V _{CEO} | $I_C=10$ mA, $I_B=0$ | 30 | | | V |
| Collector Base Voltage | V_{CBO} | I_{C} =10 μ A, I_{E} =0 | 60 | | | V |
| Emitter Base Voltage | V_{EBO} | I_{E} =10 μ A, I_{C} =0 | 5 | | | V |
| Collector Cut Off Current | I _{CBO} | V_{CB} =50V, I_{E} =0 | | | 10 | nA |
| | | V _{CB} =50V, I _E =0, T _a =150°C | | | 10 | μΑ |
| Collector Cut Off Current | I _{EBO} | V_{EB} =3 V , I_{C} =0 | | | 10 | nA |

| | | | 2N2221 | 2N2222 | |
|-----------------|-----------------|--|----------|-----------|--|
| DC Current Gain | h _{FE} | *I _C =0.1mA, V _{CE} =10V | >20 | >35 | |
| | | I_C =1mA, V_{CE} =10V | >25 | >50 | |
| | | *I _C =10mA, V _{CE} =10V | >35 | >75 | |
| | | *I _C =150mA, V _{CE} =10V | 40 - 120 | 100 - 300 | |
| | | *I _C =150mA, V _{CE} =1V | >20 | >50 | |
| | | *I _C =500mA, V _{CE} =10V | >20 | >30 | |

*Pulse Test: Pulse Width \leq 300ms, Duty Cycle \leq 2%



TO-18 Metal Can Package

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

SMALL SIGNAL CHARACTERISTICS

| DESCRIPTION | SYMBOL | TEST CONDITION | MIN | TYP | MAX | UNIT |
|--------------------------------------|------------------------|---|-----|-----|-----|------|
| Collector Emitter Saturation Voltage | *V _{CE (sat)} | I _C =150mA, I _B =15mA | | | 0.4 | V |
| | | I_C =500mA, I_B =50mA | | | 1.6 | V |
| Base Emitter Saturation Voltage | *V _{BE (sat)} | I _C =150mA, I _B =15mA | | | 1.3 | V |
| | | I_C =500mA, I_B =50mA | | | 2.6 | V |
| Transition Frequency | **f _T | I _C =20mA, V _{CE} =20V, f=100MHz | 250 | | | MHz |
| Output Capacitance | C _{obo} | V _{CB} =10V, I _E =0, f=100KHz | | | 8.0 | pF |
| Input Capacitance | C _{ibo} | V_{BE} =0.5V, I_{C} =0, f=100KHz | | | 30 | pF |

SWITCHING TIME

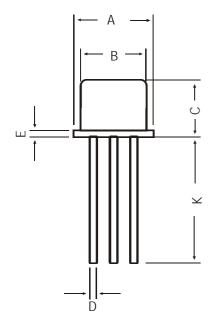
| OWITOTIME TIME | | | | | | |
|----------------|----------------|---|-----|-----|-----|------|
| DESCRIPTION | SYMBOL | TEST CONDITION | MIN | TYP | MAX | UNIT |
| Delay Time | t _d | I _C =150mA, I _{B1} =15mA, | | | 10 | ns |
| Rise Time | t _r | V_{CC} =30V, $V_{BE(off)}$ =0.5V | | | 25 | ns |
| Storage Time | t _s | I _C =150mA, I _{B1} = | | | 225 | ns |
| Fall Time | t _f | I_{B2} =15mA, V_{CC} =30V | | | 60 | ns |

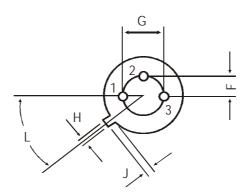
^{*}Pulse Test: Pulse Width ≤ 300ms, Duty Cycle ≤ 2%

^{**} f_T is defined as the frequency at which Ih_{fe}I extrapolates to unity

TO-18 Metal Can Package

TO-18 Metal Can Package





| DIM | MIN | MAX | | | |
|-----|---------------------|---|--|--|--|
| Α | 5.24 | 5.84 | | | |
| В | 4.52 | 4.97 | | | |
| С | 4.31 | 5.33 | | | |
| D | 0.40 | 0.53 | | | |
| Е | _ | 0.76 | | | |
| F | | 1.27 | | | |
| G | | 2.97 | | | |
| Н | 0.91 | 1.17 | | | |
| J | 0.71 | 1.21 | | | |
| K | 12.70 | _ | | | |
| L | 45 DEG | | | | |
| | A B C D E F G H J K | A 5.24 B 4.52 C 4.31 D 0.40 E — F — G — H 0.91 J 0.71 K 12.70 | | | |



PIN CONFIGURATION

- 1. EMITTER
- 2. BASE3. COLLECTOR

Packing Detail

| PACKAGE | STANDARD PACK | | INNER CARTO | N BOX | OUTER CARTON BOX | | |
|---------|------------------------|---------------|------------------|-------|-------------------|-----|--------|
| | Details Net Weight/Qty | | Size | Qty | Size | Qty | Gr Wt |
| TO-18 | 1K∕polybag | 350 gm/1K pcs | 3" x 7.5" x 7.5" | 5K | 17" x 15" x 13.5" | 80K | 34 kgs |

Notes 2N2221 2N2222

TO-18 Metal Can Package

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.

Telephone + 91-11-2579 6150, 5141 1112 Fax + 91-11-2579 5290, 5141 1119 email@cdil.com www.cdilsemi.com